DATE APPROVAL

17L615 WK

REVISIONS

DESCRIPTION

UPGRADED TO CLASS A WITH CHANGE PER

REVISED PER TORR 20618

TDRR 17369

## REQUIREMENTS:

#### 1. GENERAL:

- A. INTERPRET DRAWING IN ACCORDANCE WITH STANDARDS PRESCRIBED BY MIL-D-70327.
- EXCEPT AS. B. JUNITS SHALL MEET THE REQUIREMENTS OF MIL-S-19500 AND IN ADDITION TO THE REQUIREMENTS, SPECIFIED HEREIN.
- C. SUPPLIER SHALL CONFORM TO THE QUALITY ASSURANCE PROVISIONS CONTAINED IN ND 1015404, CLASS 2.
- D. UNITS SHALL BE CAPABLE OF MEETING THE QUALIFICATION REQUIREMENTS OF ND 1002051.

## E. MARKING:

- (1) PARTS SHALL BE PERMANENTLY AND LEGIBLY MARKED, IN ACCORDANCE WITH ND 1002019, WITH THE NASA PART NUMBER (DRAWING NUMBER AND REVISION LETTER) OR AS MANY SIGNIFICANT DIGITS AS POSSIBLE (E.G. 6310). OTHER MARKING SUCH AS MANUFACTURER'S IDENTIFICATION AND TYPE NUMBER IS PERMISSIBLE.
- F. PREPARATION FOR DELIVERY SHALL BE IN ACCORDANCE WITH ND 1002215. CLASS I. CODE 2.
  - (1) MARKING OF SHIPPING CONTAINERS SHALL CONFORM TO THE MARKING OF UNIT AND INTERMEDIATE PACKAGES AND THE METHODS OF MARKING AS SPECIFIED IN NO 1002215.

## 2. ACCEPTANCE AND INSPECTION:

# A. MECHANICAL PROPERTIES:

- (1) DIMENSIONS: AS DELINEATED HEREIN.
- -8. SEAL TEST: THE UNITS SHALL BE SUBJECTED TO A HELIUM OR RADIFLO LEAK DETECTION TEST WITH A SENSITIVITY OF AT LEAST 1 X 10-8 CC/ATM/SEC AND A HOT GLYCERINE BUBBLE TEST FOR GROSS LEAKS. THE LEAK TEST SHALL BE PERFORMED IN ACCORDANCE D. QUALITY ASSURANCE REQUIREMENTS: WITH MIL-STD-202C METHOD 112. TEST CONDITION C SHALL BE USED FOR THE HELIUM OR RADIFLO TEST. TEST CONDITION A SHALL BE USED FOR THE GROSS LEAK TEST EXCEPT THAT GLYCERINE SHALL REPLACE THE MINERAL OIL. A LEAKAGE RATE OF 1 X 10-8 CC-ATM-SEC OR GREATER SHALL CONSTITUTE A FAILURE.
  - ELECTRICAL CHARACTERISTICS: PER TABLES I, II, AND III AS LISTED BELOW:
  - (1) PRE-ELECTRICAL TEST PROCESSING: ON LOTS OF 500 OR LESS, THE TESTS OF TABLE I SHALL BE PERFORMED IN THE SEQUENCE INDICATED BEFORE THE TESTS OF TABLE II.
  - (2) ELECTRICAL TESTING: THE TESTS LISTED IN TABLE II SHALL BE PERFORMED AS LISTED BELOW:

COLLECTOR CUTOFF CURRENT COLLECTOR-BASE BREAKDOWN VOLTAGE EMITTER-BASE BREAKDOWN VOLTAGE EMITTER-BASE REVERSE CURRENT COLLECTOR-EMITTER SUSTAINING VOLTAGE COLLECTOR-EMITTER CURRENT COLLECTOR-EMITTER THRESHOLD CURRENT DIRECT CURRENT GAIN BASE-EMITTER SATURATION VOLTAGE COLLECTOR-EMITTER SATURATION VOLTAGE COLLECTOR CAPACITANCE TURN-ON AND TURN-OFF TIME

PROCURE, ONLY: FROM. APPROVED. SOURCES, LISTED. IN. NO. 1002034. FOR THIS DRAWING.

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SYM

QUALITY DEMONSTRATION TESTING: PER TABLE III ON LOTS MORE THAN 500 UNITS USING ACCEPTABLE UNITS FROM SUBGROUP 2 OF TABLE II FOR SUBGROUP 2, 3, AND 4 OF TABLE III. SUBGROUPS 1 AND 5 MAY USE ELECTRICAL REJECTS FROM THE SAME LOT.

- D. VENDOR SUPPLIED DATA: EACH SHIPMENT OF PARTS SHALL BE ACCOMPANIED BY THE FOLLOWING DOCUMENTATION.
  - (1) CERTIFICATE OF COMPLIANCE WITH LEAD MATERIAL REQUIREMENT.
  - (2) CERTIFICATE OF COMPLIANCE WITH ND 1015404, CLASS 2.
  - CERTIFICATE OF COMPLIANCE WITH PARA.2 .C(1) OR 2.C(3). UNITS USED IN QUALITY DEMONSTRATION TESTS OF TABLE III WILL NOT BE SHIPPED AS PART OF THE DELIVERY SCHEDULE BUT WILL BE FORWARDED UNDER SEPARATE COVER WITH TEST DATA FOR EACH LOT SHIPMENT.

### 3. DESIGN:

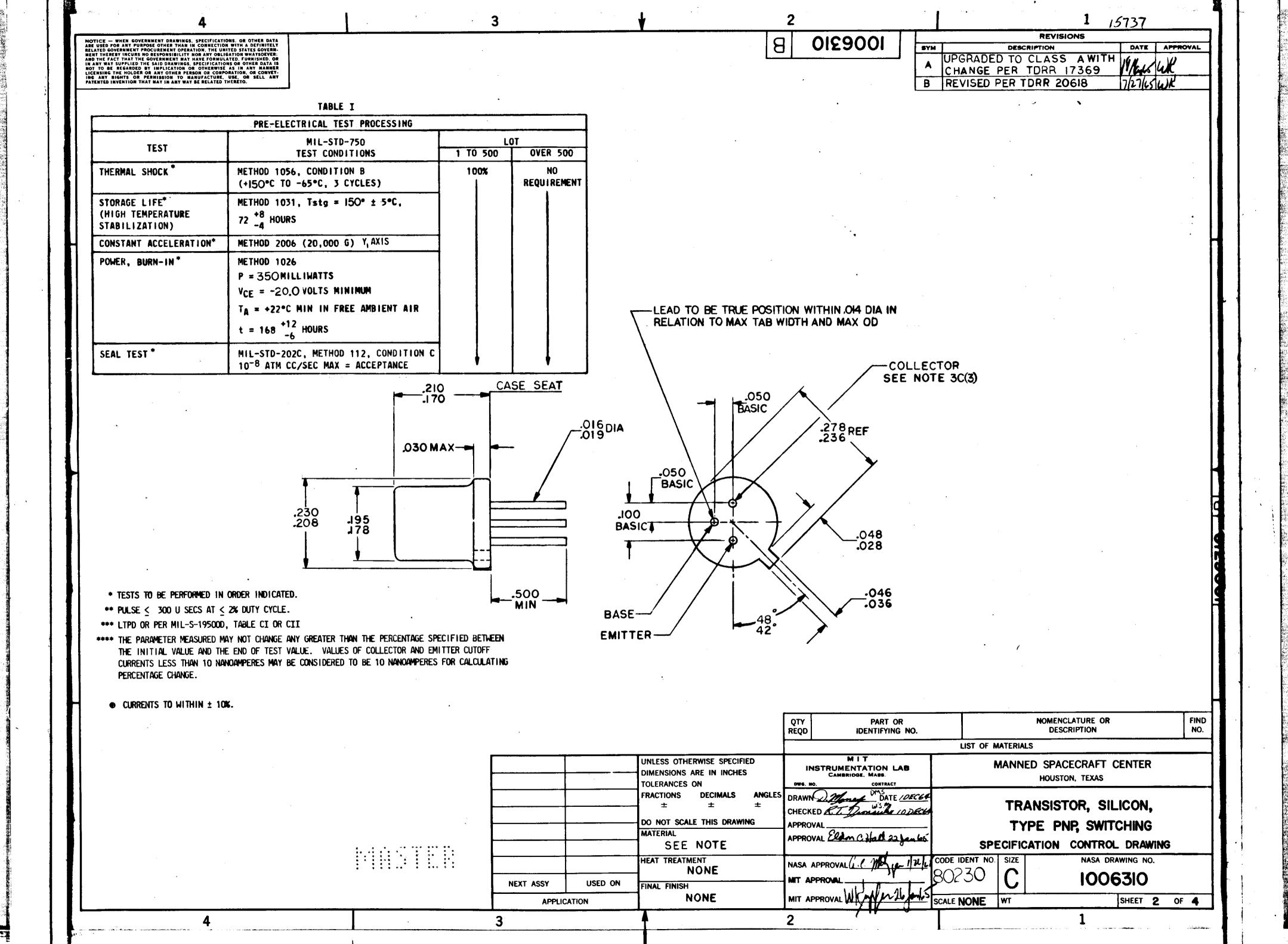
- A. STORAGE LIFE: INDEFINITE WHEN STORED AT TEMPERATURES BETWEEN -65°C AND +150°C.
- B. ABSOLUTE MAXIMUM RATINGS AT 25°C AMBIENT.
  - (1) COLLECTOR-EMITTER VOLTAGE (VCEO): 40 VDC
  - (2) COLLECTOR-BASE VOLTAGE (VCBO): 60 VDC
  - (3) EMITTER-BASE VOLTAGE (VEBO): 5 VDC
  - (4) COLLECTOR CURRENT (IC): 600 MILLIAMPERES
  - (5) THERMAL RESISTANCE, JUNCTION-CASE (OJC): 50°C/WATT
  - (6) THERMAL RESISTANCE, JUNCTION-AMBIENT (014): 350°C/WATT
  - (7) TEMPERATURE RANGE, JUNCTION, OPERATING: -65°C TO +150°C.
  - (8) TEMPERATURE RANGE, STORAGE: -65°C TO +150°C

# C. CONSTRUCTION:

- (1) SEMICONDUCTOR: SILICON PLANAR EPITAXIAL PNP
- (2) CASE: METAL CAN AND METAL HEADER HERMETICALLY SEALED (JEDEC TO-18)
- (3) COLLECTOR SHALL BE ELECTRICALLY CONNECTED TO THE CASE INTERNALLY.
- (4) LEAD MATERIAL: WELDABLE, GOLD PLATED, ANNEALED IRON-NICKEL-COBALT (KOVAR) ALLOY IN ACCORDANCE WITH ND 1015402.

- (1) LOT DEFINITION: A GROUP OF PARTS IN A SINGLE PROCUREMENT SELECTED FROM A SINGLE CONTINUOUS PRODUCTION RUN USING LIKE MATERIALS WHICH ARE CONTROLLED USING A PROCESS WHICH IS THE SAME FROM THE BEGINNING TO THE END OF THE RUN.
- (2) INSPECTION CONDITIONS: UNLESS OTHERWISE SPECIFIED, ALL IN-SPECTIONS SHALL BE MADE AT AN AMBIENT TEMPERATURE OF +25° ± 3°C.

		REQD IDENTIFYING NO.	DESCRIPTION NO.				
			LIST OF MATERIALS				
	UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES TOLERANCES ON	M I T INSTRUMENTATION LAB CAMBRIDGE, MASS. DWG. NO. CONTRACT	MANNED SPACECRAFT CENTER HOUSTON, TEXAS				
	FRACTIONS DECIMALS ANGLES  ± ±  DO NOT SCALE THIS DRAWING  MATERIAL  SEE NOTE	CHECKED R.T. Diometer 9 Dece APPROVAL	TRANSISTOR, SILICON,  TYPE PNP, SWITCHING  SPECIFICATION CONTROL DRAWING				
MENT ACCY LICED ON	HEAT TREATMENT NONE	INIACA ADDOONIAI / ' MIR 5 ti ' TILI I	code ident no. size NASA DRAWING NO. 1006310				
APPLICATION	FINAL FINISH NONE	1.1 Kinte 16 late	SCALE NONE WT SHEET   OF 4				



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NOTICE — WHEN GOVERNMENT DRAWINGS, SPECIFICATIONS OR OTHER DATA ARE USED FOR ANY PURPOSE OTHER THAN IN CONNECTION WITH A DEFINITELY RELATED GOVERNMENT PROCUREMENT OPERATION. THE UNITED STATES GOVERNMENT THEREBY INCURS NO RESPONSIBILITY NOR ANY OBLIGATION WHATSOEVER, AND THE FACT THAT THE GOVERNMENT MAY HAVE FORMULATED, FURNISHED, OR IN ANY WAY SUPPLIED THE SAID DRAWINGS, SPECIFICATIONS OR OTHER DATA 18 NOT TO BE RECARDED BY IMPLICATION OR OTHERWISE AS IN ANY MANNER LICENSING THE HOLDER OR ANY OTHER PERSON OR CORPORATION, OR CONVEYING ANY RIGHTS OR PERMISSION TO MANUFACTURE, USE, OR SELL ANY PATENTED INVENTION THAT MAY IN ANY WAY BE RELATED THERETO.

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REVISED PER TDRR 20618 7/2/65 WK

		TABLE II			<u> </u>			
		ACCEPTANCE INSPECTION				•		
TEST	SYMBOL	MIL-STD-750 TEST CONDITIONS		MIT	UNITS	LOT		
1231	JANOL			MAX		1 TO 500	OVER 500	
SUBGROUP 1 VISUAL AND MECHANICAL EXAMINATION		METHOD 2071 (SEE NOTE 2 A (3))				LTPD = 10 MAX ACC NO.= 3	LTPD*** 10 Max acc no.= 3	
SUBGROUP 2  COLLECTOR CUTOFF CURRENT  COLLECTOR CUTOFF CURRENT 150°C  COLLECTOR-BASE BREAKDOWN VOLTAGE  EMITTER-BASE REVERSE CURRENT  EMITTER-BASE BREAKDOWN VOLTAGE  COLLECTOR-EMITTER SUSTAINING VOLTAGE**  COLLECTOR-EMITTER CURRENT RES. RETURN  COLLECTOR-EMITTER THRESHOLD CURRENT  DC CURRENT GAIN **  DC CURRENT GAIN **	ICBO ICBO BVCBO IEBO BVEBO VCEO SUST ICER ICES hFE	VCB = -50 V; IE = 0  VCB = -50 V; IE = 0  IC = -10 uA; IE = 0  VEB = -3 V; IC = 0  IE = -10 uA; I <sub>C</sub> = 0  IC = -10 mA PULSED  IB = 0  VCE = -20 V; R <sub>BE</sub> = 100 K  V <sub>BE</sub> = -0; V <sub>CE</sub> = -50 V  IC = -150 mA; V <sub>CE</sub> = -10 V  IC = -1 mA; V <sub>CE</sub> = -10 V	60 5 60 80 100		NA UA V UA V	100%	LTPD = 2 (COMBINED) MAX ACC NO.= 3	
DC CURRENT GAIN  DC CURRENT GAIN  **  BASE-EMITTER SATURATION VOLTAGE  **  COLLECTOR-EMITTER SATURATION VOLTAGE  **  COLLECTOR-EMITTER SATURATION VOLTAGE  COLLECTOR CAPACITANCE	hFE NBE(sat) VCE(sat) VCE(sat) Cob	1 <sub>C</sub> =-500 <sub>m</sub> A: V <sub>CE</sub> = -10 V	30 0.7		V V V PF			
TURN OF TIME	t <sub>on</sub>	$I_{B1} \approx 30^{\circ} \text{mA}; I_{C} \approx 300^{\circ} \text{mA}$ $t_{W} > 400 \text{ nsec}$ $2\% \text{ PUTY CYCLE}$ $I_{B1} = I_{B2} \approx 30^{\circ} \text{mA}; I_{C} \approx 300^{\circ} \text{mA}$ $t_{W} > 400 \text{ nsec}$ $2\% \text{ DUTY CYCLE}$		40 100	NSEC NSEC	LTPD = 5 MAX ACC = 0	LTPD = 5 MAX ACC = 0	

				QTY REQD	PART OR IDENTIFYING NO.			ENCLATURE OR ESCRIPTION	FIND NO.	
			,		······································	LIST OF M	IATERIALS			
	DIMENSIONS ARE IN TOLERANCES ON FRACTIONS DECI		UNLESS OTHERWISE SPECIFIED  DIMENSIONS ARE IN INCHES  TOLERANCES ON	MIT INSTRUMENTATION LAB CAMBRIDGE, MASS. DWG. NO. CONTRACT		MANNED SPACECRAFT CENTER HOUSTON, TEXAS				
			FRACTIONS DECIMALS ANGLES  ± ± ±  DO NOT SCALE THIS DRAWING	± ± CHECKED  THIS DRAWING APPROVAL	KED R.T. Drouge by 9 DOLLA	TRANSISTOR, SILICON, TYPE PNP, SWITCHING SPECIFICATION CONTROL DRAWING				
	NEXT ASSY	USED ON	HEAT TREATMENT NONE FINAL FINISH	1	APPROVAL	code ident no. 802 30	C	NASA DRAWING NO. 1006310		
	APPLIC	CATION	NONE	MIT A	APPROVALLA CHIPTO 26 165	SCALE NONE	WT	SHEET 3	OF <b>4</b>	
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	QUALITY DEMONSTRATION TESTS				
TECT	MIL-STD-750	LOT			
TEST	TEST CONDITIONS	1 TO 500	OVER 500		
SUBGROUP 1 PHYSICAL DIMENSIONS	METHOD 2066	NO REQUIREMENTS	*** LTPD = 20 MAX ACC NO.= 1		
SUBGROUP 2* THERMAL SHOCK SEAL TEST	METHOD 1056-I CONDITION B (+150°C TO -65°C, 5 CYCLES)		*** LTPD = 10 (COMBINED) MAX ACC NO.= 3		
SUBGROUP 3*		1 1			
STORAGE LIFE	METHOD 1031.1 Tstg = 150° ± 5°C, 1000 HOURS		*** LTPD = 10 (COMBINED) MAX ACC NO.= 3		
SHOCK	METHOD 2016-1 1500 G, 0.5 MSEC 5 BLOWS EACH IN X1, Y1, Y2, Z1 DIRECTIONS, 20 BLOWS TOTAL		HAX ACC NO >		
VIBRATION VARIABLE FREQUENCY	METHOD 2056, 30 G FROM 5 TO 2000 CPS LIMITED TO 0.12 DOUBLE AMPLITUDE, 3 CYCLES, 15 MINUTES PER CYCLE MINIMUM.				
CONSTANT ACCELERATION	METHOD 2006, 20,000 G YAXIS				
SUBGROUP 4 OPERATION LIFE	METHOD 1026-1 P = 350 MILLIWATTS V <sub>CE</sub> =-20 VOLTS MINIMUM T <sub>A</sub> = +22°C MIN IN FREE AMBIENT AIR t = 1000 HOURS		ኢ***= 10 MAX ACC NO.= 3		
SUBGROUP 5*	METHOD 2036	]	***		
LEAD TENSTON (COND A ) LEAD FATIGUE (COND E )			LTPD = 20 (COMBINED) MAX ACC NO.= 3		

## TABLE III (CONTINUED)

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TEST	SYMBOL	TEST CONDITION	LIMIT
END POINTS FOR SUBGROUP 2 COLLECTOR CUTOFF CURRENT EMITTER -BASE REVERSE CURRENT DC CURRENT GAIN	I <sub>CBO</sub> I <sub>EBO</sub> hFE	V <sub>CB</sub> = -50 V, I <sub>C</sub> = 0 V <sub>EB</sub> = -3 V, I <sub>C</sub> = 0 V <sub>CE</sub> = -10 V, I <sub>C</sub> = -10 mA	±50% **** ±50% **** ±10% ****
END POINTS FOR SUBGROUPS 3 AND 4 COLLECTOR CUTOFF CURRENT EMITTER-BASE REVERSE CURRENT DC CURRENT GAIN	ICBO Iebo MFE	$V_{CB} = -50V$ , $I_{E} = 0$ $V_{EB} = -3 V$ , $I_{C} = 0$ $V_{CE} = -10V$ , $I_{C} = -10 \text{ mA}$	±100% ***** ±100% ***** ±20% ****

QTY REQD NOMENCLATURE OR DESCRIPTION IDENTIFYING NO. LIST OF MATERIALS M I T
INSTRUMENTATION LAB
CAMBRIDGE, MASS. UNLESS OTHERWISE SPECIFIED MANNED SPACECRAFT CENTER DIMENSIONS ARE IN INCHES HOUSTON, TEXAS TOLERANCES ON CHECKED R.T. DWSML PRECE FRACTIONS DECIMALS ANGLES TRANSISTOR, SILICON, DO NOT SCALE THIS DRAWING TYPE PNP, SWITCHING SEE NOTE APPROVAL Ella CHER 22 Janes SPECIFICATION CONTROL DRAWING NASA APPROVAL CODE IDENT NO. SIZE

MIT APPROVAL HEAT TREATMENT NASA DRAWING NO. NONE 1006310 **NEXT ASSY** USED ON FINAL FINISH MIT APPROVAL W NONE SCALE NONE WT SHEET 4 OF 4 **APPLICATION** 2